AMENDMENTS TO THE CLAIMS

Please amend claims 12 and 20, and add new claim 27 as indicated below. No new matter is believed to be introduced as a result of the aforementioned amendments and new claim.

- 1. (Original) A vertical cavity surface emitting laser (VCSEL) comprising:
 - a substrate;
 - a first mirror situated on said substrate;
 - an active region situated on said first mirror;
 - a second mirror situated on said active region;
 - a first contact situated on a first portion of said second mirror;
 - a thermally conductive layer situated on a second portion of said second mirror; and wherein said thermally conductive layer is thermally connected to said first contact.
- 2. (Original) The VCSEL of claim 1, further comprising a thermally conductive metal connected to said first contact.
- 3. (Original) The VCSEL of claim 2, wherein said substrate comprises InP.
- 4. (Original) A VCSEL comprising:
 - a top mirror; and
 - a thermally conductive cover on said top mirror.
- 5. (Original) The VCSEL of claim 4, further comprising a thermally conductive material connected to said thermally conductive cover.
- 6. (Original) The VCSEL of claim 5, wherein said top mirror comprises InP based material.

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- 7. (Original) The VCSEL of claim 6, wherein said top mirror is designed for reflecting some radiation having a wavelength be 1200 and 1800 nanometers (nm).
- 8. (Original) The VCSEL of claim 7, wherein said thermally conductive cover comprises a material from a group of GaP, SiN, AlN, BN, SiC, diamond, and the like.
- 9. The VCSEL of claim 8, wherein said thermally conductive material (Original) comprises a material from a group of gold and like materials.
- 10. (Original) The VCSEL of claim 4, further comprising a heatsink connected to said thermally conductive cover.
- 11. The VCSEL of claim 10, further comprising a first contact situated on (Original) said top mirror and thermally connected to said thermally conductive cover and said heat sink.
- 12. (Currently amended) A VCSEL comprising:
 - a substrate;
 - a first mirror situated on said substrate;
 - an active region situated on said first mirror;
 - a second mirror situated on said active region;
 - a contact situated on a first portion of said [[first]] second mirror;
- a low thermal conductive covering situated on a second portion of said [[first]] second mirror; and
 - a thermally conductive material connected to said contact.

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The VCSEL of claim 12, wherein said substrate comprises InP. 13. (Original)

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- 14. (Original) The VCSEL of claim 13, wherein said first mirror comprises a material nearly lattice matched with the InP of said substrate.
- 15. (Original) The VCSEL of claim 14, wherein said thermally conductive material is for conducting heat from said second mirror via said contact.
- 16. (**Original**) The VCSEL of claim 15, wherein said thermally conductive material comprises material from a group of gold and other like materials.
- 17. (Original) The VCSEL of claim 16, wherein the VCSEL is for emitting a laser light having a wavelength between 1200 nm and 1800 nm.
- 18. (Original) The VCSEL of claim 15, wherein said contact comprises a thermally conductive material.
- 19. (Original) The VCSEL of claim 18, wherein said thermally conductive material is connected to a heat sink.
- 20. (Currently amended) A VCSEL comprising:
 - a substrate;
 - a first semiconductor mirror situated on said substrate;
 - an active region situated on said first semiconductor mirror;
 - a second semiconductor mirror situated on said active region;
 - a dielectric mirror situated on said second semiconductor mirror;
 - a first contact situated on said [[first]] second semiconductor mirror; and
- a metal interconnect connected to said [[first]] second contact and in contact with an edge of said dielectric mirror; and

wherein said dielectric mirror comprises thermally conductive material.

21. (Withdrawn) A VCSEL comprising:

a substrate;

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a first mirror situated on said substrate;

an active region situated on said first mirror;

a second mirror situated on said active region;

and

a thermally conductive material in contact with an edge of said second mirror.

- 22. (Withdrawn) The VCSEL of claim 21, further comprising a thermally conductive layer situated on said second mirror.
- 23. (Withdrawn) The VCSEL of claim 22, further comprising a thermally conductive material situated on said thermally conductive layer.
- 24. (Withdrawn) The VCSEL of claim 21, further comprising a contact situated on said second mirror.
- 25. (Withdrawn) The VCSEL of claim 24, further comprising a thermally conductive layer on said second mirror.
- 26. (Withdrawn) The VCSEL claim 25, further comprising a thermally conductive material situated on said second mirror and said contact.

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- 27. (New) A vertical cavity surface emitting laser, comprising:
 - a substrate;
 - a first mirror situated on said substrate;
 - an active region situated on said first mirror;
 - a second region situated on said active region;
 - a contact situated on said second mirror; and
- a thermally conductive structure arranged for thermal communication with a portion of at least one of: the first mirror; and, the second mirror.

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